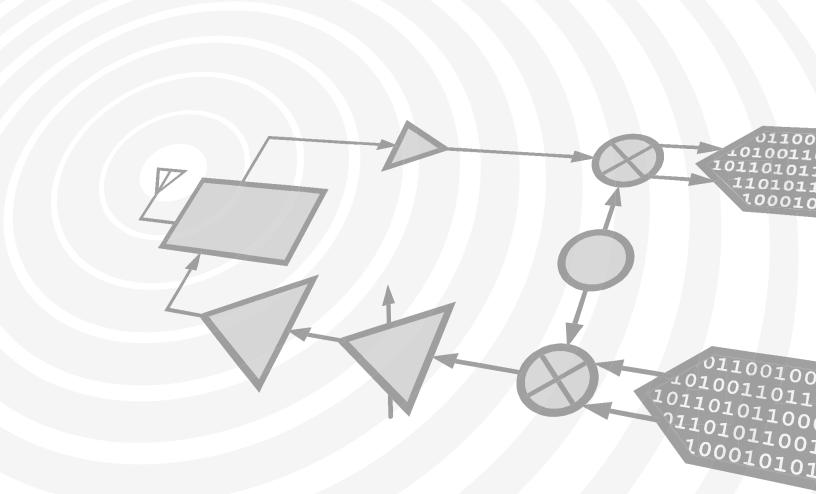
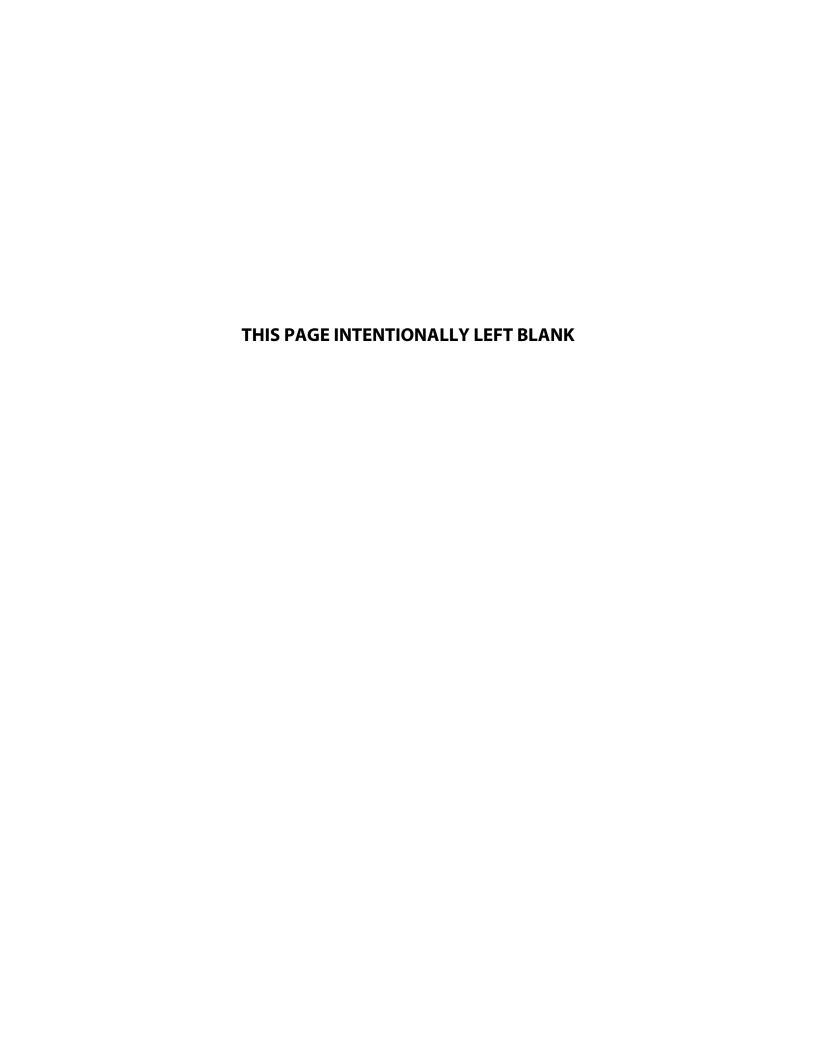




Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED







Typical Applications

The HMC128 is ideal for:

- Microwave & VSAT Radios
- Test Equipment
- Military EW, ECM, C3I
- Space Telecom

Features

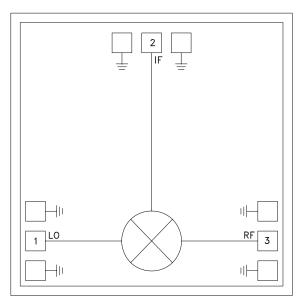
Conversion Loss: 7 dB

LO to RF and IF Isolation: >36 dB

Input IP3: +18 dBm No DC Bias Required

Die Size: 1.45 x 1.45 x 0.1 mm

Functional Diagram



General Description

The HMC128 is a miniature double-balanced mixer chip that can be used as an upconverter or downconverter. The device is a passive diode/balun type mixer with high dynamic range. Noise figure is essentially equal to the conversion loss. The mixer can handle larger signal levels than active mixers due to the high third order intercept. MMIC implementation provides exceptional balance in the circuit resulting in high LO/RF and LO/IF isolations. This mixer can operate over a wide LO Drive input of +9 to +15 dBm.

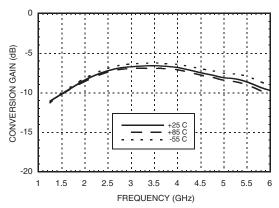
Electrical Specifications, $T_A = +25^{\circ}$ C, LO Drive = +15 dBm*

Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF & LO	1.8 - 5.0		GHz	
Frequency Range, IF	DC - 3			GHz
Conversion Loss		7	10	dB
Noise Figure (SSB)		7	10	dB
LO to RF Isolation	35	42		dB
LO to IF Isolation	27	36		dB
IP3 (Input)	15	18		dBm
IP2 (Input)	45	50		dBm
1 dB Gain Compression (Input)	5	10		dBm

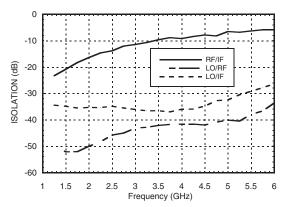
^{*} Unless otherwise noted, all measurements performed as downconverter, IF = 100 MHz



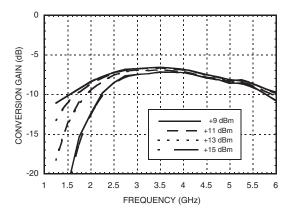
Conversion Gain vs . Temperature @ LO = +15 dBm



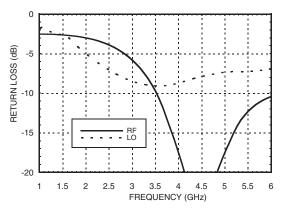
Isolation @ LO = +15 dBm



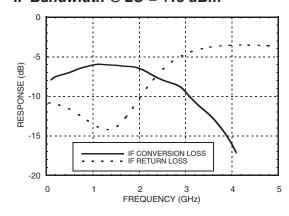
Conversion Gain vs. LO Drive



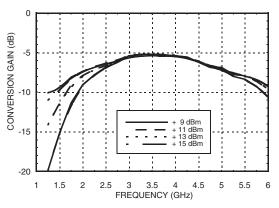
LO and RF Return Loss



IF Bandwidth @ LO = +15 dBm

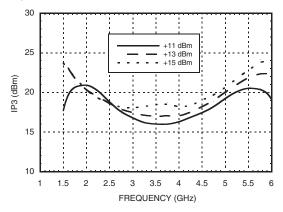


Upconverter Performance Conversion Gain vs. LO Drive

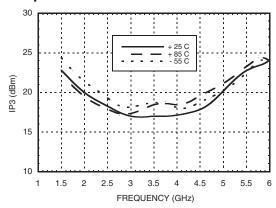




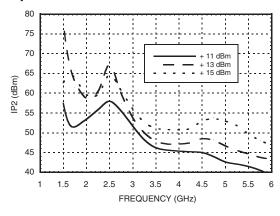
Input IP3 vs. LO Drive



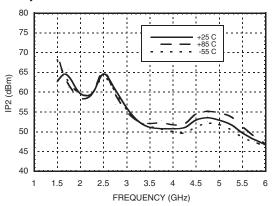
Input IP3 vs. Temperature @ LO = +15 dBm



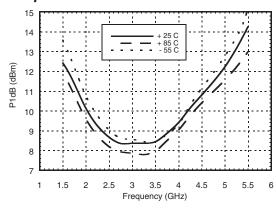
Input IP2 vs LO Drive



Input IP2 vs.
Temperature @ LO = +15 dBm



Input P1dB vs. Temperature @ LO = +15 dBm



Harmonics of LO

	nLO Spur @ RF Port			
LO Freq. (GHz)	1	2	3	4
1.5	54	42	54	54
2.0	48	41	50	66
2.5	47	41	44	76
3.5	40	50	52	75
4.5	40	60	51	65
5.5	38	60	46	63

LO = +13 dBm

All values in dBc below input LO level measured at RF port.



MxN Spurious @ IF Port

	nLO				
mRF	0	1	2	3	4
0	xx	5.6	30.3	11.1	34.5
1	2.8	0	23.3	31.5	29.1
2	62.3	58.6	57.8	60.3	75.8
3	74.3	>85	74.3	65.8	74.3
4	>85	>85	>85	>85	>85

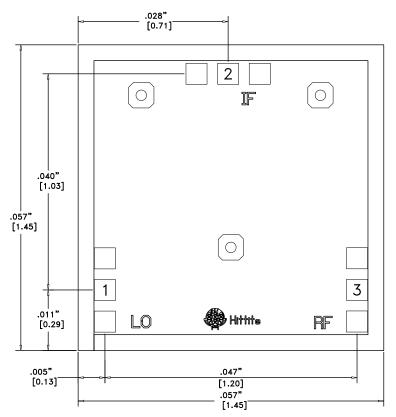
RF Freq.= 3.5 GHz @ -10 dBm LO Freq.= 3.4 GHz @ +13 dBm All values in dBc below IF power level. Measured as downconverter

Absolute Maximum Ratings

LO Drive	+27 dBm
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



Outline Drawing



Die Packaging Information [1]

Standard	Alternate
WP-3 (Waffle Pack)	[2]

[1] Refer to the "Packaging Information" section for die packaging dimensions.

[2] For alternate packaging information contact Hittite Microwave Corporation.

NOTES:

- 1. ALL DIMENSIONS ARE IN INCHES [MM]
- 2. BOND PADS ARE .004" SQUARE
- 3. TYPICAL BOND PAD SPACING CENTER TO CENTER IS .006"
- .1 EXCEPT AS SHOWN
- 4. DIE THICKNESS = .004" [.100 MM]
- 5. BACKSIDE METALIZATION: GOLD
- 6. BACKSIDE METAL IS GROUND
- 7. BOND PAD METALIZATION: GOLD

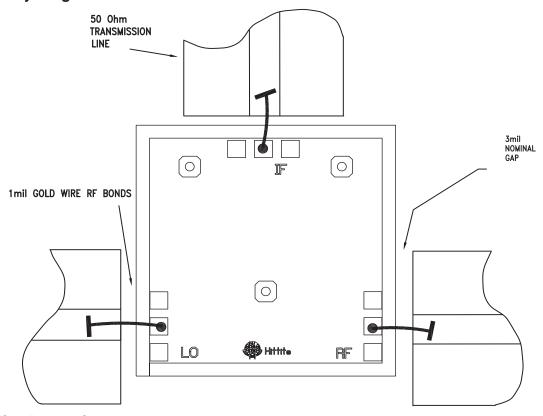


Pad Descriptions

Pad Number	Function	Description	Interface Schematic
1	LO	This pin is DC coupled and matched to 50 Ohms.	LO 0————————————————————————————————————
2	IF	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC this pin must not source or sink more than 2mA of current or die non-function and possible die failure will result.	IFO THE STATE OF T
3	RF	This pin is DC coupled and matched to 50 Ohms.	LO 0————————————————————————————————————
	GND	The backside of the die must connect to RF ground.	GND =



Assembly Diagram



Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

Static Sensitivity: Follow ESD precautions to protect against ESD strikes.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

Mounting

The chip is back-metallized and can be die mounted with AuSn eutectic preforms or with electrically conductive epoxy. The mounting surface should be clean and flat.

Eutectic Die Attach: A 80/20 gold tin preform is recommended with a work surface temperature of 255 °C and a tool temperature of 265 °C. When hot 90/10 nitrogen/hydrogen gas is applied, tool tip temperature should be 290 °C. DO NOT expose the chip to a temperature greater than 320 °C for more than 20 seconds. No more than 3 seconds of scrubbing should be required for attachment.

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

Wire Bonding

Ball or wedge bond with 0.025 mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 °C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31 mm (12 mils).

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 CSM4T
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